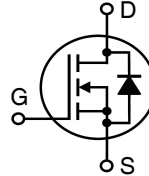


X-Class HiPerFET™ Power MOSFET

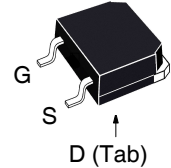
IXFT32N100XHV IXFH32N100X IXFK32N100X

$V_{DSS} = 1000V$
 $I_{D25} = 32A$
 $R_{DS(on)} \leq 220m\Omega$

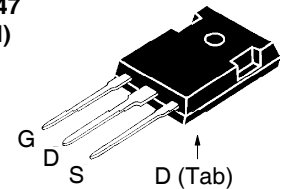
N-Channel Enhancement Mode
Avalanche Rated



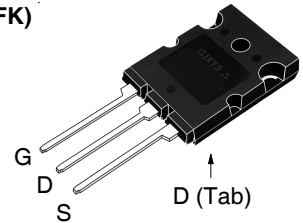
TO-268HV
(IXFT..HV)



TO-247
(IXFH)



TO-264
(IXFK)



G = Gate D = Drain
S = Source Tab = Drain

| Symbol | Test Conditions | Maximum Ratings | |
|---------------|--|-----------------|------------|
| V_{DSS} | $T_J = 25^\circ C$ to $150^\circ C$ | 1000 | V |
| V_{DGR} | $T_J = 25^\circ C$ to $150^\circ C$, $R_{GS} = 1M\Omega$ | 1000 | V |
| V_{GSS} | Continuous | ± 30 | V |
| V_{GSM} | Transient | ± 40 | V |
| I_{D25} | $T_C = 25^\circ C$ | 32 | A |
| I_{DM} | $T_C = 25^\circ C$, Pulse Width Limited by T_{JM} | 64 | A |
| I_A | $T_C = 25^\circ C$ | 16 | A |
| E_{AS} | $T_C = 25^\circ C$ | 2 | J |
| dv/dt | $I_S \leq I_{DM}$, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ C$ | 50 | V/ns |
| P_D | $T_C = 25^\circ C$ | 890 | W |
| T_J | | -55 ... +150 | $^\circ C$ |
| T_{JM} | | 150 | $^\circ C$ |
| T_{stg} | | -55 ... +150 | $^\circ C$ |
| T_L | Maximum Lead Temperature for Soldering | 300 | $^\circ C$ |
| T_{SOLD} | 1.6 mm (0.062in.) from Case for 10s | 260 | $^\circ C$ |
| M_d | Mounting Torque (TO-247 & TO-264) | 1.13 / 10 | Nm/lb.in |
| Weight | TO-268HV | 4 | g |
| | TO-247 | 6 | g |
| | TO-264 | 10 | g |

| Symbol | Test Conditions ($T_J = 25^\circ C$, Unless Otherwise Specified) | Characteristic Values | | |
|--------------|---|-----------------------|------|--------------------|
| | | Min. | Typ. | Max. |
| BV_{DSS} | $V_{GS} = 0V$, $I_D = 1mA$ | 1000 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 4mA$ | 3.5 | | 6.0 V |
| I_{GSS} | $V_{GS} = \pm 30V$, $V_{DS} = 0V$ | | | ± 100 nA |
| I_{DSS} | $V_{DS} = V_{DSS}$, $V_{GS} = 0V$ $T_J = 125^\circ C$ | | | 50 μA 3 mA |
| $R_{DS(on)}$ | $V_{GS} = 10V$, $I_D = 0.5 \cdot I_{D25}$, Note 1 | | | 220 m Ω |

Features

- International Standard Packages
- Low $R_{DS(ON)}$ and Q_G
- Avalanche Rated
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

| Symbol | Test Conditions ($T_J = 25^\circ\text{C}$, Unless Otherwise Specified) | Characteristic Values | | |
|--------------|--|-----------------------|------|-------------------------|
| | | Min. | Typ. | Max |
| g_{fs} | $V_{DS} = 20\text{V}$, $I_D = 16\text{A}$, Note 1 | 14 | 23 | S |
| R_{Gi} | Gate Input Resistance | | 0.6 | Ω |
| C_{iss} | } $V_{GS} = 0\text{V}$, $V_{DS} = 25\text{V}$, $f = 1\text{MHz}$ | | 4075 | pF |
| C_{oss} | | | 520 | pF |
| C_{rss} | | | 10 | pF |
| | Effective Output Capacitance | | | |
| $C_{o(er)}$ | Energy related } $V_{GS} = 0\text{V}$ | | 140 | pF |
| $C_{o(tr)}$ | Time related } $V_{DS} = 0.8 \cdot V_{DSS}$ | | 585 | pF |
| $t_{d(on)}$ | } Resistive Switching Times $V_{GS} = 10\text{V}$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_D = 0.5 \cdot I_{D25}$ $R_G = 2\Omega$ (External) | | 29 | ns |
| t_r | | | 12 | ns |
| $t_{d(off)}$ | | | 80 | ns |
| t_f | | | 12 | ns |
| $Q_{g(on)}$ | } $V_{GS} = 10\text{V}$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_D = 0.5 \cdot I_{D25}$ | | 130 | nC |
| Q_{gs} | | | 27 | nC |
| Q_{gd} | | | 70 | nC |
| R_{thJC} | | | | 0.14 $^\circ\text{C/W}$ |
| R_{thCS} | TO-247 | | 0.21 | $^\circ\text{C/W}$ |
| | TO-264P | | 0.15 | $^\circ\text{C/W}$ |

Source-Drain Diode

| Symbol | Test Conditions ($T_J = 25^\circ\text{C}$, Unless Otherwise Specified) | Characteristic Values | | |
|----------|--|-----------------------|------|---------------|
| | | Min. | Typ. | Max |
| I_S | $V_{GS} = 0\text{V}$ | | | 32 A |
| I_{SM} | Repetitive, pulse Width Limited by T_{JM} | | | 128 A |
| V_{SD} | $I_F = I_S$, $V_{GS} = 0\text{V}$, Note 1 | | | 1.4 V |
| t_{rr} | } $I_F = 16\text{A}$, $-di/dt = 100\text{A}/\mu\text{s}$ $V_R = 100\text{V}$ | | 200 | ns |
| Q_{RM} | | | 1.5 | μC |
| I_{RM} | | | 15 | A |

Note 1. Pulse test, $t \leq 300\mu\text{s}$, duty cycle, $d \leq 2\%$.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

| | | | | | | | | | |
|-----------|-----------|-----------|-----------|-------------|-------------|-------------|-------------|-------------|-------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665 | 6,404,065B1 | 6,683,344 | 6,727,585 | 7,005,734B2 | 7,157,338B2 |
| 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123B1 | 6,534,343 | 6,710,405B2 | 6,759,692 | 7,063,975B2 | |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728B1 | 6,583,505 | 6,710,463 | 6,771,478B2 | 7,071,537 | |

Fig. 1. Output Characteristics @ $T_J = 25^\circ\text{C}$

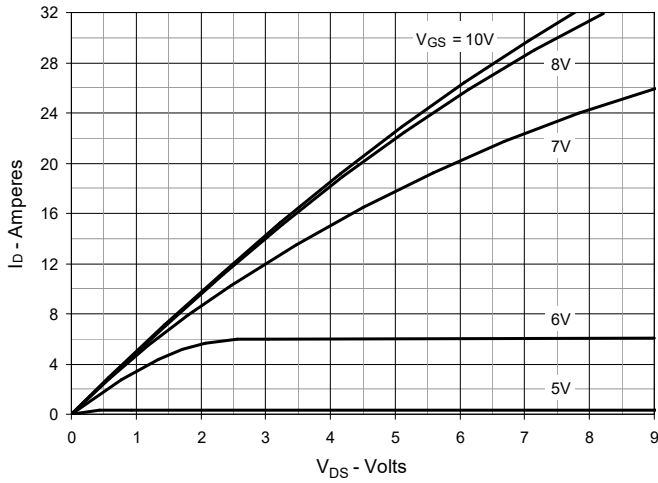


Fig. 2. Extended Output Characteristics @ $T_J = 25^\circ\text{C}$

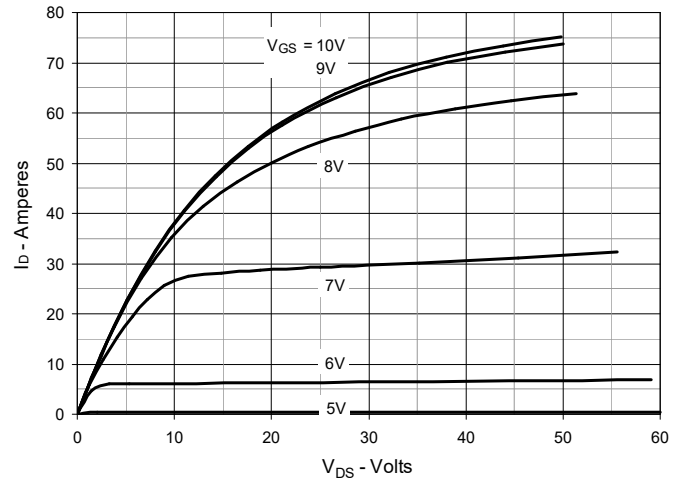


Fig. 3. Output Characteristics @ $T_J = 125^\circ\text{C}$

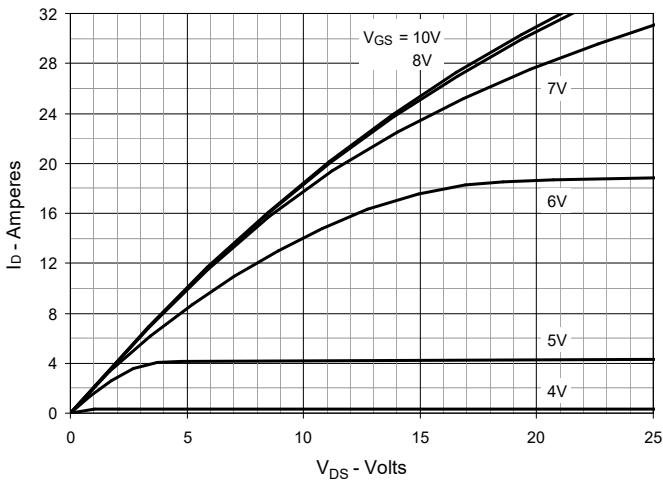


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 16A$ Value vs. Junction Temperature

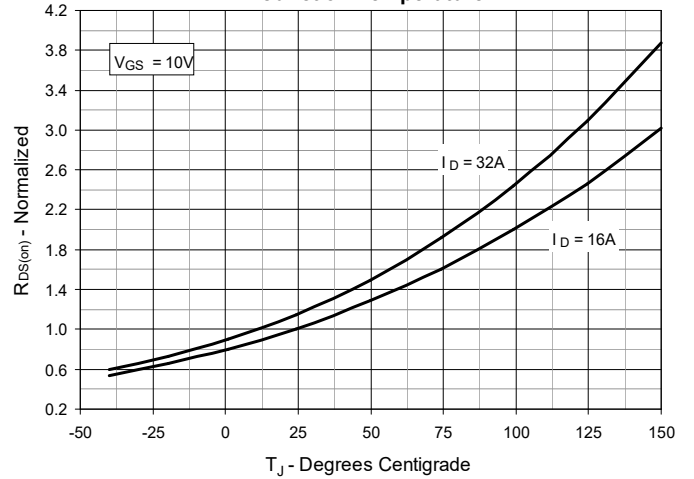


Fig. 5. $R_{DS(on)}$ Normalized to $I_D = 16A$ Value vs. Drain Current

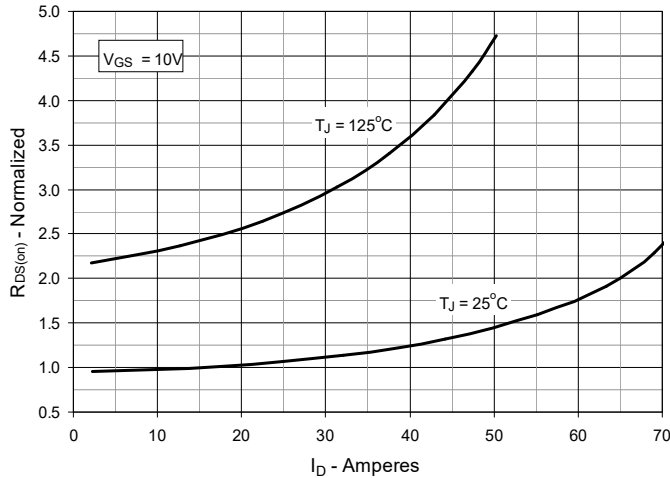


Fig. 6. Normalized Breakdown & Threshold Voltages vs. Junction Temperature

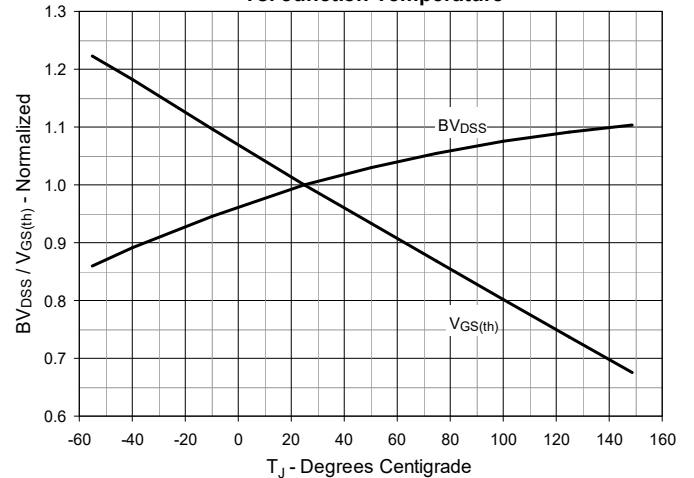


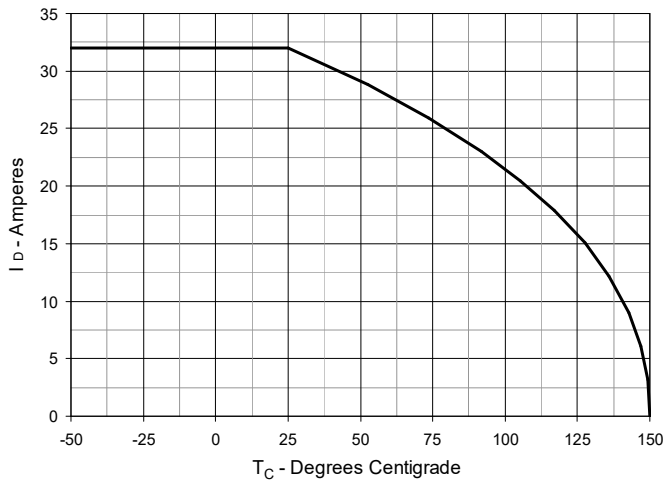
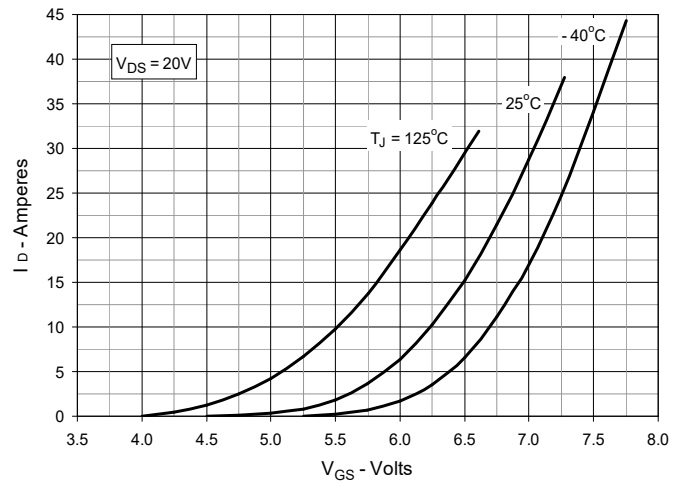
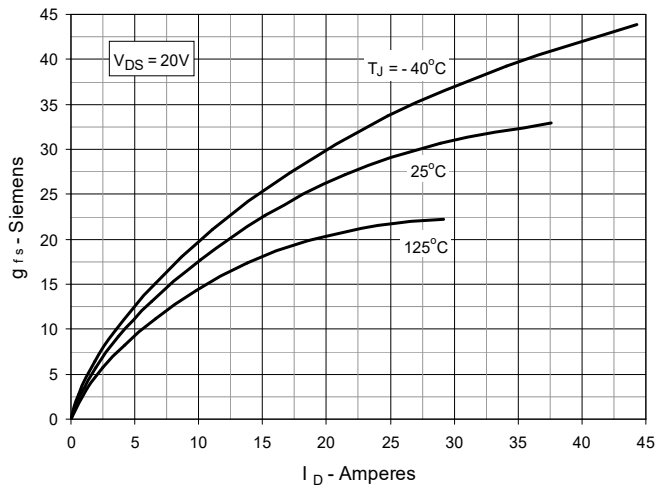
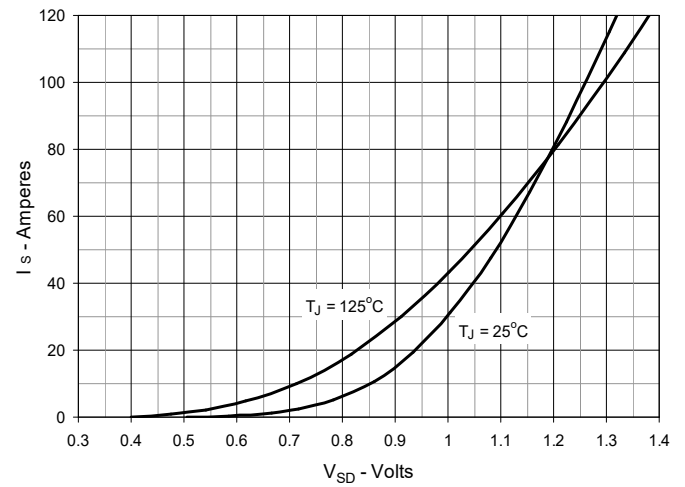
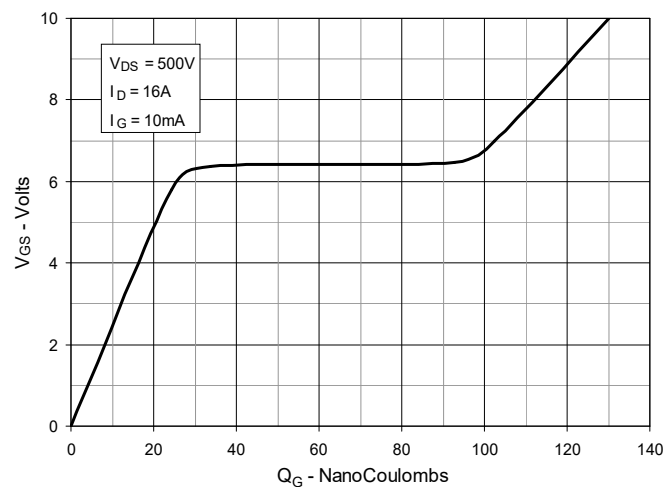
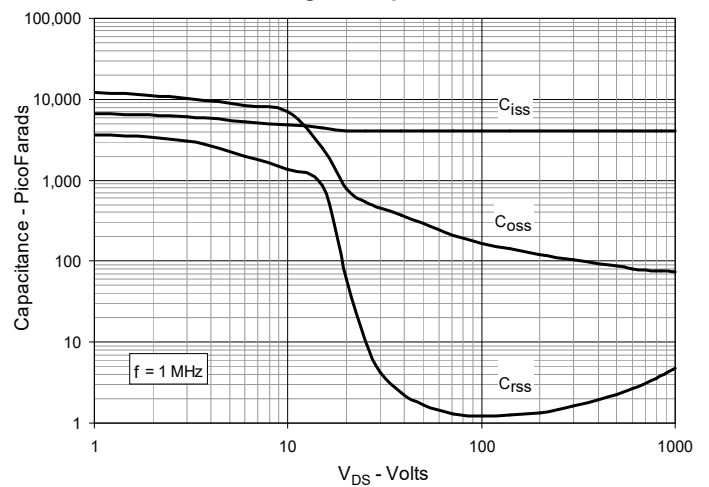
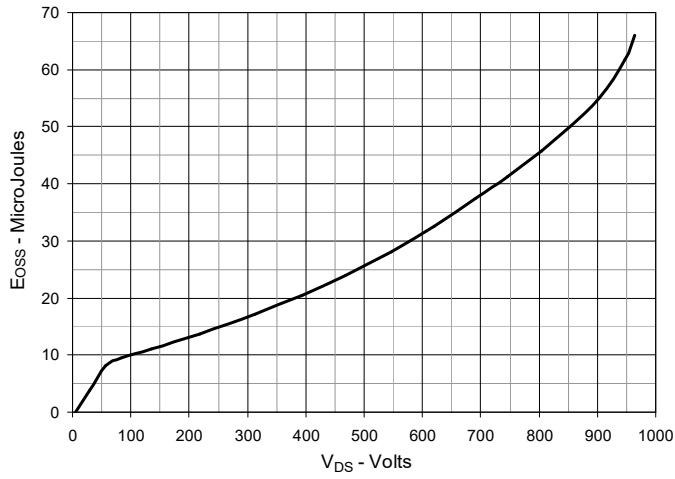
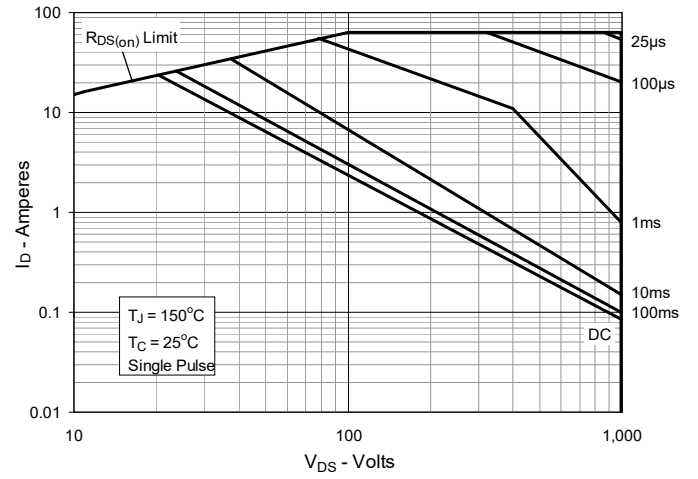
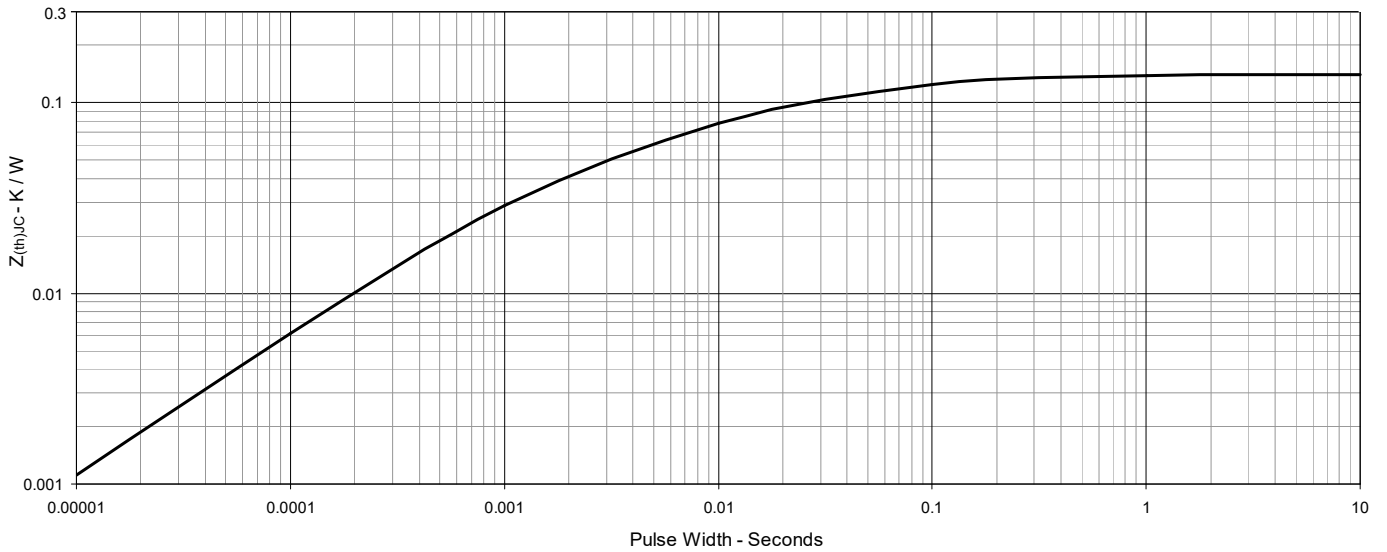
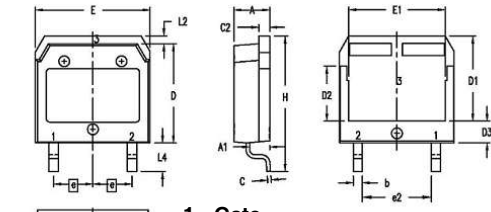
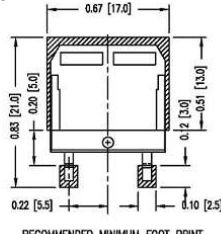
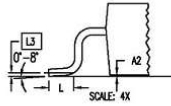
Fig. 7. Maximum Drain Current vs. Case Temperature

Fig. 8. Input Admittance

Fig. 9. Transconductance

Fig. 10. Forward Voltage Drop of Intrinsic Diode

Fig. 11. Gate Charge

Fig. 12. Capacitance


Fig. 13. Output Capacitance Stored Energy

Fig. 14. Forward-Bias Safe Operating Area

Fig. 15. Maximum Transient Thermal Impedance


TO-268HV Outline



- 1 - Gate
- 2 - Source
- 3 - Drain

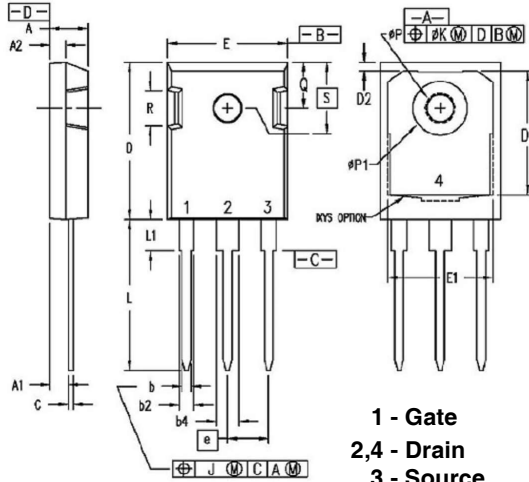


| CREEPAGE DISTANCE | | | |
|-----------------------------------|--------|-------|----------|
| DESCRIPTION | SYMBOL | MIN | DISTANCE |
| LEAD TO LEAD AIR CLEARANCE | e2 | 0.372 | 9.45mm |
| LEAD TO LEAD PKG SURFACE CREEPAGE | e2 | 0.374 | 9.50mm |
| LEAD TO BOTTOM DRAIN CREEPAGE | A1+D3 | 0.213 | 5.40mm |

| SYM | INCHES | | MILLIMETER | |
|------|--------|------|------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .193 | .201 | 4.90 | 5.10 |
| A1 | .106 | .114 | 2.70 | 2.90 |
| A2 | .001 | .010 | 0.02 | 0.25 |
| b | .045 | .057 | 1.15 | 1.45 |
| C | .016 | .026 | 0.40 | 0.65 |
| C2 | .057 | .063 | 1.45 | 1.60 |
| D | .543 | .551 | 13.80 | 14.00 |
| D1 | .465 | .476 | 11.80 | 12.10 |
| D2 | .295 | .307 | 7.50 | 7.80 |
| D3 | .114 | .126 | 2.90 | 3.20 |
| E | .624 | .632 | 15.85 | 16.05 |
| E1 | .524 | .535 | 13.30 | 13.60 |
| e | .215 | BSC | 5.45 | BSC |
| (e2) | .374 | .386 | 9.50 | 9.80 |
| H | .736 | .752 | 18.70 | 19.10 |
| L | .067 | .079 | 1.70 | 2.00 |
| L2 | .039 | .045 | 1.00 | 1.15 |
| L3 | .010 | BSC | 0.25 | BSC |
| L4 | .150 | .161 | 3.80 | 4.10 |

- NOTE:
1. This drawing meets all dimensions requirement of JEDEC outlines TO-268AA except L dimension.
 2. All metal surface are matte pure tin plated except trimmed area.
 3. [L3] is Gauge plane to measure L.
 4. These dimension do not include mold flash and they will not exceed 0.005[0.13] per side.

TO-247 Outline

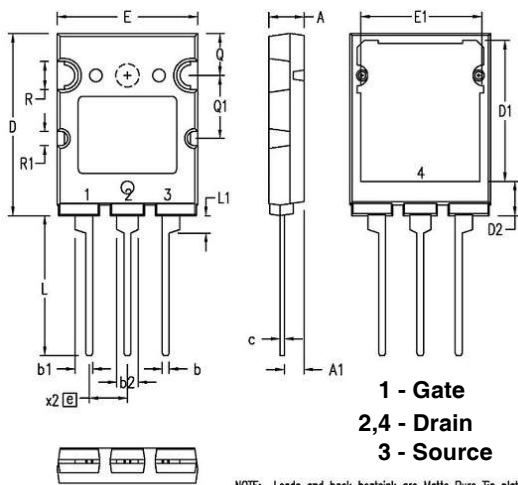


- 1 - Gate
- 2,4 - Drain
- 3 - Source

| SYM | INCHES | | MILLIMETERS | | |
|-----|--------|------|-------------|-------|-----|
| | MIN | MAX | MIN | MAX | |
| A | .190 | .205 | 4.83 | 5.21 | |
| A1 | .090 | .100 | 2.29 | 2.54 | |
| A2 | .075 | .085 | 1.91 | 2.16 | |
| b | .045 | .055 | 1.14 | 1.40 | |
| b2 | .075 | .087 | 1.91 | 2.20 | |
| b4 | .115 | .126 | 2.92 | 3.20 | |
| C | .024 | .031 | 0.61 | 0.80 | |
| D | .819 | .840 | 20.80 | 21.34 | |
| D1 | .650 | .690 | 16.51 | 17.53 | |
| D2 | .035 | .050 | 0.89 | 1.27 | |
| E | .620 | .635 | 15.75 | 16.13 | |
| E1 | .545 | .565 | 13.84 | 14.35 | |
| e | .215 | BSC | 5.45 | BSC | |
| J | -- | .010 | -- | 0.25 | |
| K | -- | .025 | -- | 0.64 | |
| L | .780 | .810 | 19.81 | 20.57 | |
| L1 | .150 | .170 | 3.81 | 4.32 | |
| øP | .140 | .144 | 3.55 | 3.65 | |
| øP1 | .275 | .290 | 6.99 | 7.37 | |
| Q | .220 | .244 | 5.59 | 6.20 | |
| R | .170 | .190 | 4.32 | 4.83 | |
| S | | .242 | BSC | 6.15 | BSC |

- NOTE: This drawing will meet all dimensions requirement of JEDEC outlines TO-247 AD (R-PSIP-F3)

TO-264 Outline



- 1 - Gate
- 2,4 - Drain
- 3 - Source

| SYM | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .185 | .209 | 4.70 | 5.30 |
| A1 | .102 | .118 | 2.60 | 3.00 |
| b | .035 | .049 | 0.90 | 1.25 |
| b1 | .091 | .106 | 2.30 | 2.70 |
| b2 | .110 | .126 | 2.80 | 3.20 |
| c | .020 | .033 | 0.50 | 0.85 |
| D | 1.012 | 1.035 | 25.70 | 26.30 |
| D1 | .783 | .799 | 19.90 | 20.30 |
| D2 | .185 | .205 | 4.70 | 5.20 |
| E | .776 | .799 | 19.70 | 20.30 |
| E1 | .661 | .677 | 16.80 | 17.20 |
| e | .215 | BSC | 5.46 | BSC |
| L | .768 | .807 | 19.50 | 20.50 |
| L1 | .091 | .106 | 2.30 | 2.70 |
| Q | .228 | .244 | 5.80 | 6.20 |
| Q1 | .346 | .362 | 8.80 | 9.20 |
| øR | .150 | .165 | 3.80 | 4.20 |
| øR1 | .071 | .087 | 1.80 | 2.20 |

NOTE: Leads and back heatsink are Matte Pure Tin plated.



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